

# Ultra-Low EMI, Filterless, 2.6W, Mono, Class D Audio Power Amplifier with E<sup>2</sup>S

## General Description

The LM48311 is a single supply, high efficiency, mono, 2.6W, filterless switching audio amplifier. The LM48311 features National's Enhanced Emissions Suppression (E<sup>2</sup>S) system, that features a unique patent-pending ultra low EMI, spread spectrum, PWM architecture, that significantly reduces RF emissions while preserving audio quality and efficiency. The E<sup>2</sup>S system improves battery life, reduces external component count, board area consumption, system cost, and simplifying design.

The LM48311 is designed to meet the demands of portable multimedia devices. Operating from a single 5V supply, the device is capable of delivering 2.6W of continuous output power to a 4Ω load with less than 10% THD+N. Flexible power supply requirements allow operation from 2.4V to 5.5V. The LM48311 features both a spread spectrum modulation scheme, and an advanced, patented edge rate control (ERC) architecture that significantly reduces emissions, while maintaining high quality audio reproduction (THD+N = 0.03%) and high efficiency ( $\eta = 88\%$ ).

The LM48311 features high efficiency compared to conventional Class AB amplifiers, and other low EMI Class D amplifiers. When driving an 8Ω speaker from a 5V supply, the device operates with 88% efficiency at  $P_O = 1W$ . The gain of the LM48311 is internally set to 6dB, further reducing external component count. A low power shutdown mode reduces supply current consumption to 0.01μA.

Advanced output short circuit protection with auto-recovery prevents the device from being damaged during fault conditions. Superior click and pop suppression eliminates audible transients on power-up/down and during shutdown.

## Key Specifications

■ Efficiency at 3.6V, 400mW into 8Ω	85% (typ)
■ Efficiency at 5V, 1W into 8Ω	88% (typ)
■ Quiescent Power Supply Current at 5V	3.1mA
■ Power Output at $V_{DD} = 5V, R_L = 4\Omega$	
THD+N ≤ 10%	2.6W (typ)
THD+N ≤ 1%	2.1W (typ)
■ Power Output at $V_{DD} = 5V, R_L = 8\Omega$	
THD+N ≤ 10%	1.6W (typ)
THD+N ≤ 1%	1.3W (typ)
■ Shutdown current	0.01μA (typ)

## Features

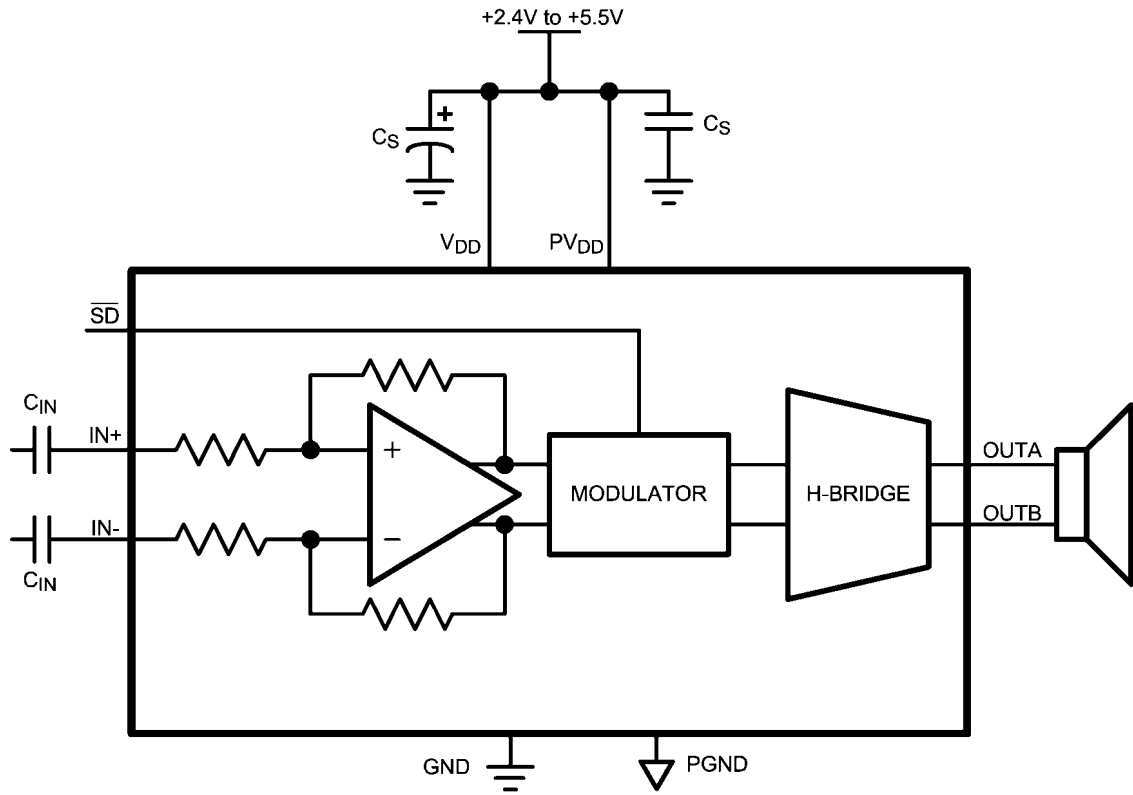
- Passes FCC Class B Radiated Emissions with 20 inches of cable
- E<sup>2</sup>S System Reduces EMI while Preserving Audio Quality and Efficiency
- Output Short Circuit Protection with Auto-Recovery
- No output filter required
- Internally Configured Gain (6dB)
- Low power shutdown mode
- Minimum external components
- "Click and pop" suppression
- Micro-power shutdown
- Available in space-saving microSMD package

## Applications

- Mobile phones
- PDAs
- Laptops

LM48311 Ultra-Low EMI, Filterless, 2.6W, Mono, Class D Audio Power Amplifier with E<sup>2</sup>S

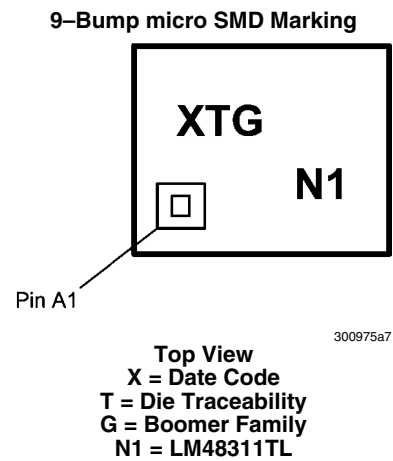
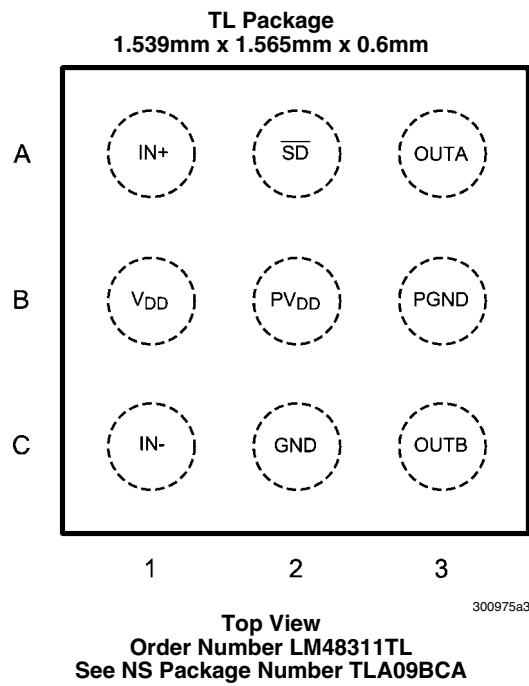
## Typical Application



300975a8

FIGURE 1. Typical Audio Amplifier Application Circuit

## Connection Diagrams



## Ordering Information

Order Number	Package	Package DWG #	Transport Media	MSL Level	Green Status
LM48311TL	9 Bump micro SMD	TLA09BCA	250 units on tape and reel	1	RoHS & no Sb/Br
LM48311TLX	9 Bump micro SMD	TLA09BCA	3000 units on tape and reel	1	RoHS & no Sb/Br

## Pin Descriptions

**TABLE 1. Bump Description**

Pin	Name	Description
A1	IN+	Non-Inverting Input
A2	$\overline{SD}$	Active Low Shutdown Input. Connect to $V_{DD}$ for normal operation.
A3	OUTA	Non-Inverting Output
B1	$V_{DD}$	Power Supply
B2	$PV_{DD}$	H-Bridge Power Supply
B3	PGND	Power Ground
C1	IN-	Inverting Input
C2	GND	Ground
C3	OUTB	Inverting Output

## Absolute Maximum Ratings (Note 1, Note 2)

2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage	6.0V
Storage Temperature	-65°C to +150°C
Input Voltage	-0.3V to $V_{DD} + 0.3V$
Power Dissipation <small>(Note 3)</small>	Internally Limited
ESD Rating <small>(Note 4)</small>	2000V
ESD Rating <small>(Note 5)</small>	200V

Junction Temperature	150°C
Thermal Resistance	
$\theta_{JA}$	70°C/W
Soldering Information	See AN-1112 "Micro SMD Wafer Level Chip Scale Package."

## Operating Ratings (Note 1, Note 2)

Temperature Range	
$T_{MIN} \leq T_A \leq T_{MAX}$	$-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$
Supply Voltage ( $V_{DD}$ , $PV_{DD}$ )	$2.4V \leq V_{DD} \leq 5.5V$

## Electrical Characteristics $V_{DD} = PV_{DD} = 5V$ (Note 2, Note 8)

The following specifications apply for  $A_V = 6\text{dB}$ ,  $R_L = 8\Omega$ ,  $f = 1\text{kHz}$ , unless otherwise specified. Limits apply for  $T_A = 25^\circ\text{C}$ .

Symbol	Parameter	Conditions	LM48311			Units (Limits)
			Min <small>(Note 7)</small>	Typ <small>(Note 6)</small>	Max <small>(Note 7)</small>	
$V_{DD}$	Supply Voltage Range	$V_{IN} = 0$	2.4		5.5	V
$I_{DD}$	Quiescent Power Supply Current	$V_{IN} = 0$ , $R_L = \infty$ $V_{DD} = 3.6V$ $V_{DD} = 5V$		2.7 3.1	3.4 3.9	mA mA
$I_{SD}$	Shutdown Current	Shutdown enabled		0.01	1.0	$\mu\text{A}$
$V_{OS}$	Differential Output Offset Voltage	$V_{IN} = 0$	-3	1	3	mV
$V_{IH}$	Logic Input High Voltage		1.4			V
$V_{IL}$	Logic Input Low Voltage				0.4	V
CMVR	Common Mode Input Voltage Range		0		$V_{DD} - 0.25$	V
$T_{WU}$	Wake Up Time			7.5		ms
$f_{SW}$	Switching Frequency	$\text{SYNC\_IN} = V_{DD}$ (Spread Spectrum)		300±30		kHz
$A_V$	Gain		5	6	7	dB
$R_{IN}$	Input Resistance		17	20		$\text{k}\Omega$
$R_{SD}$	Input Resistance ( $\overline{\text{SD}}$ )	$\overline{\text{SD}}$ to GND		300		$\text{k}\Omega$
$P_O$	Output Power	$R_L = 4\Omega$ , THD = 10% $f = 1\text{kHz}$ , 22kHz BW $V_{DD} = 5V$ $V_{DD} = 3.6V$ $V_{DD} = 2.5V$		2.6 1.3 555		W W mW
		$R_L = 8\Omega$ , THD = 10% $f = 1\text{kHz}$ , 22kHz BW $V_{DD} = 5V$ $V_{DD} = 3.6V$ $V_{DD} = 2.5V$		1.6 800 354		W mW mW
		$R_L = 4\Omega$ , THD = 1% $f = 1\text{kHz}$ , 22kHz BW $V_{DD} = 5V$ $V_{DD} = 3.6V$ $V_{DD} = 2.5V$		2.1 1 446		W W mW
		$R_L = 8\Omega$ , THD = 1% $f = 1\text{kHz}$ , 22kHz BW $V_{DD} = 5V$ $V_{DD} = 3.6V$ $V_{DD} = 2.5V$	1.1	1.3 640 286		W (min) mW mW

Symbol	Parameter	Conditions	LM48311			Units (Limits)
			Min (Note 7)	Typ (Note 6)	Max (Note 7)	
THD+N	Total Harmonic Distortion + Noise	$P_O = 200\text{mW}$ , $R_L = 8\Omega$ , $f = 1\text{kHz}$		0.03		%
		$P_O = 100\text{mW}$ , $R_L = 8\Omega$ , $f = 1\text{kHz}$		0.03		%
PSRR	Power Supply Rejection Ratio (Input Referred)	$V_{\text{RIPPLE}} = 200\text{mV}_{\text{p-p}}$ Sine, Inputs AC GND, $C_{\text{IN}} = 1\mu\text{F}$ $f_{\text{RIPPLE}} = 217\text{Hz}$ $f_{\text{RIPPLE}} = 1\text{kHz}$		78		dB
					76	
CMRR	Common Mode Rejection Ratio (Input Referred)	$V_{\text{RIPPLE}} = 1\text{V}_{\text{p-p}}$ $f_{\text{RIPPLE}} = 217\text{Hz}$		86		dB
$\eta$	Efficiency	$V_{\text{DD}} = 5\text{V}$ , $P_{\text{OUT}} = 1\text{W}$		88		%
		$V_{\text{DD}} = 3.6\text{V}$ , $P_{\text{OUT}} = 400\text{mW}$		85		%
SNR	Signal to Noise Ratio	$P_O = 1\text{W}$		97		dB
$\epsilon_{\text{OS}}$	Output Noise (Input Referred)	Un-weighted		28		$\mu\text{V}$
		A-weighted		22		$\mu\text{V}$

**Note 1:** "Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur, including inoperability and degradation of device reliability and/or performance. Functional operation of the device and/or non-degradation at the *Absolute Maximum Ratings* or other conditions beyond those indicated in the *Recommended Operating Conditions* is not implied. The *Recommended Operating Conditions* indicate conditions at which the device is functional and the device should not be operated beyond such conditions. All voltages are measured with respect to the ground pin, unless otherwise specified.

**Note 2:** The *Electrical Characteristics* tables list guaranteed specifications under the listed *Recommended Operating Conditions* except as otherwise modified or specified by the *Electrical Characteristics Conditions* and/or Notes. Typical specifications are estimations only and are not guaranteed.

**Note 3:** The maximum power dissipation must be derated at elevated temperatures and is dictated by  $T_{\text{JMAX}}$ ,  $\theta_{\text{JA}}$ , and the ambient temperature,  $T_{\text{A}}$ . The maximum allowable power dissipation is  $P_{\text{DMAX}} = (T_{\text{JMAX}} - T_{\text{A}}) / \theta_{\text{JA}}$  or the number given in *Absolute Maximum Ratings*, whichever is lower.

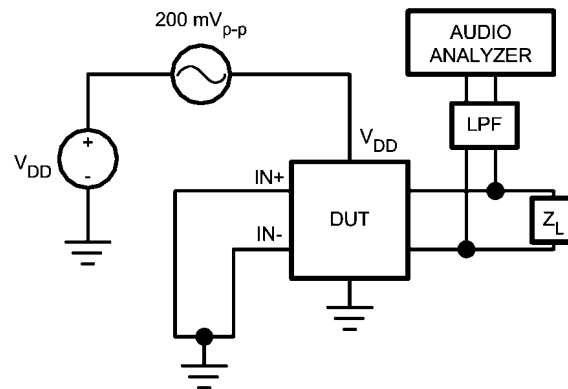
**Note 4:** Human body model, applicable std. JESD22-A114C.

**Note 5:** Machine model, applicable std. JESD22-A115-A.

**Note 6:** Typical values represent most likely parametric norms at  $T_{\text{A}} = +25^\circ\text{C}$ , and at the *Recommended Operation Conditions* at the time of product characterization and are not guaranteed.

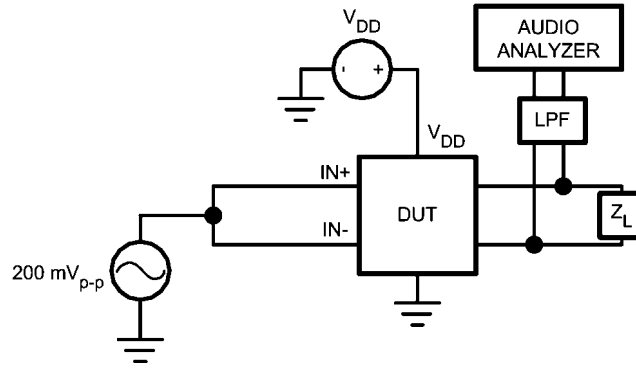
**Note 7:** Datasheet min/max specification limits are guaranteed by test or statistical analysis.

**Note 8:**  $R_L$  is a resistive load in series with two inductors to simulate an actual speaker load. For  $R_L = 8\Omega$ , the load is  $15\mu\text{H} + 8\Omega + 15\mu\text{H}$ . For  $R_L = 4\Omega$ , the load is  $15\mu\text{H} + 4\Omega + 15\mu\text{H}$ .



30097528

FIGURE 2. PSRR Test Circuit

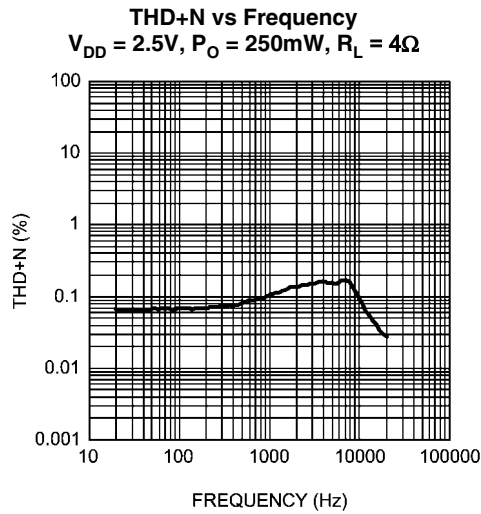


30097527

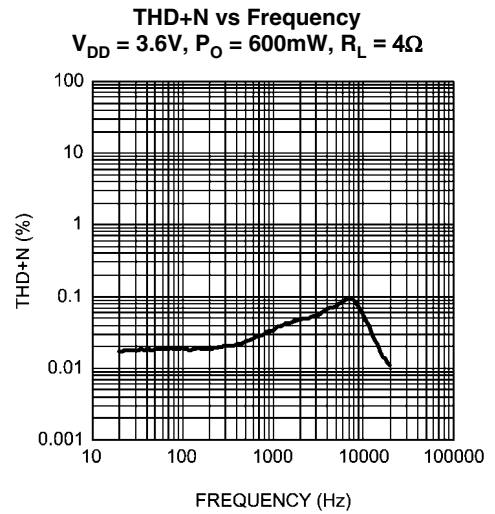
FIGURE 3. CMRR Test Circuit

## Typical Performance Characteristics

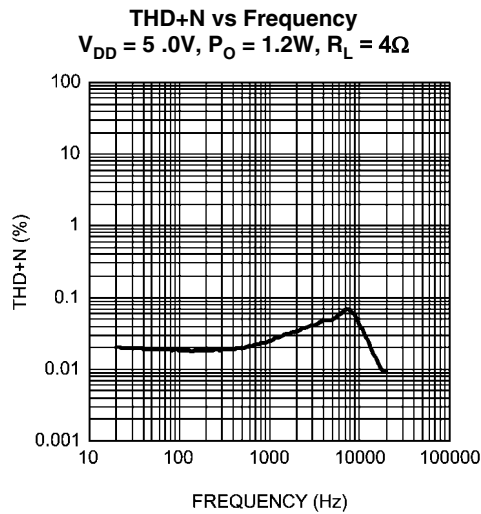
For all performance graphs, the Output Gains are set to 0dB, unless otherwise noted.



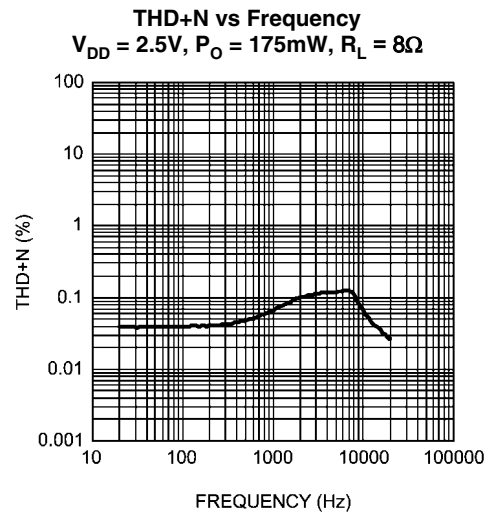
30097504



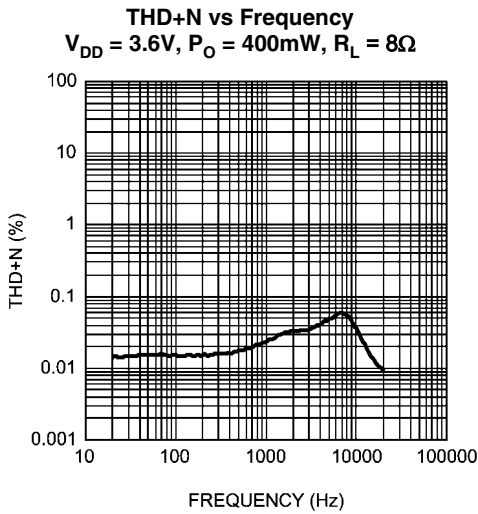
30097505



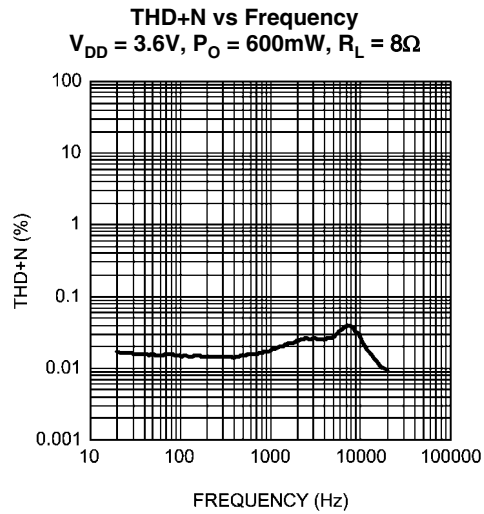
30097506



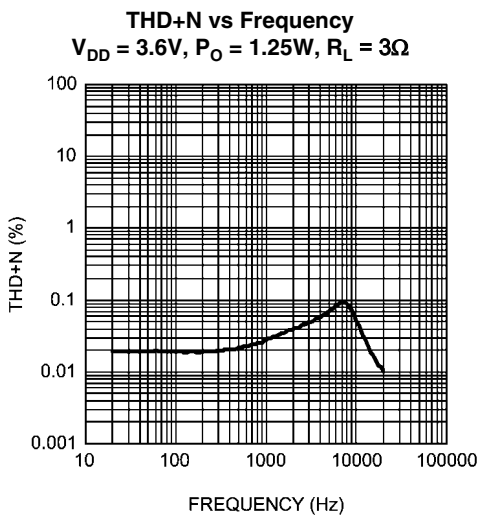
30097507



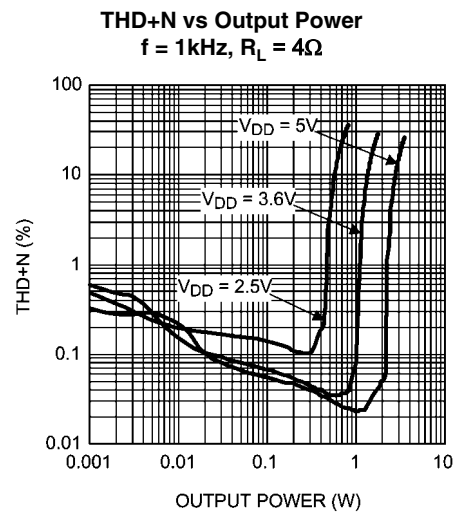
30097508



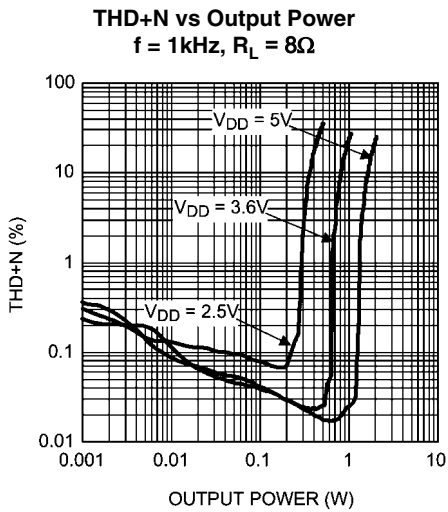
30097509



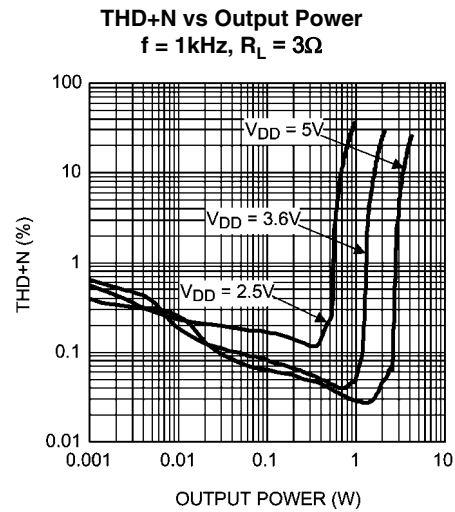
30097510



30097501

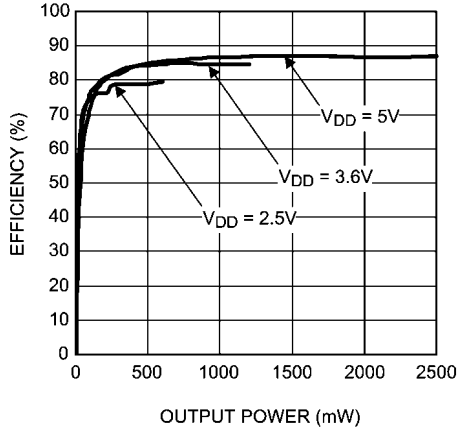


30097502



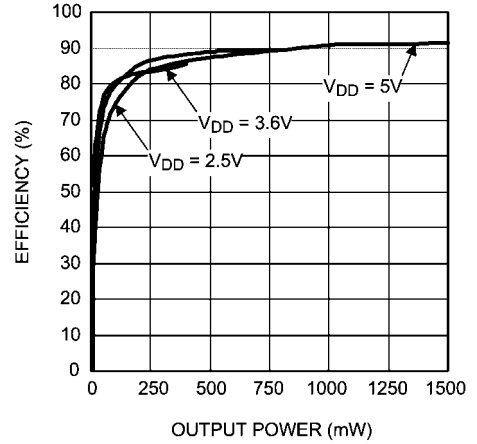
30097503

**Efficiency vs Output Power**  
 $f = 1\text{kHz}, R_L = 4\Omega$



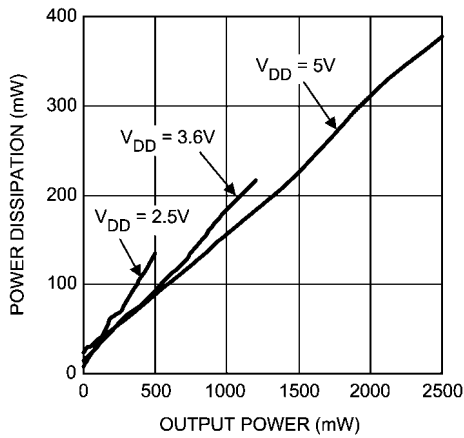
30097511

**Efficiency vs Output Power**  
 $f = 1\text{kHz}, R_L = 8\Omega$



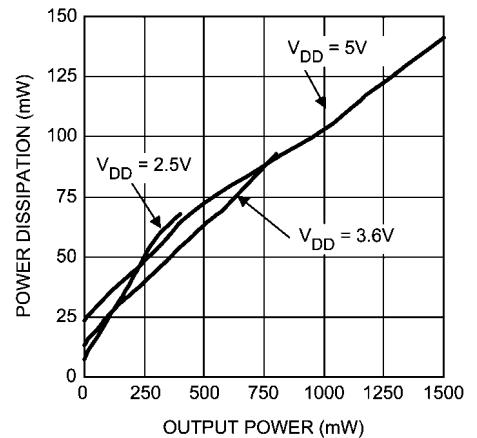
30097512

**Power Dissipation vs Output Power**  
 $f = 1\text{kHz}, R_L = 4\Omega$



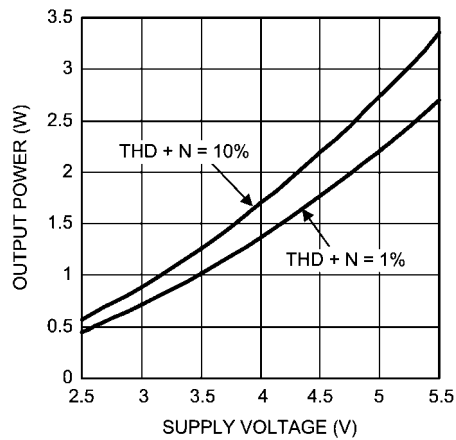
30097513

**Power Dissipation vs Output Power**  
 $f = 1\text{kHz}, R_L = 8\Omega$



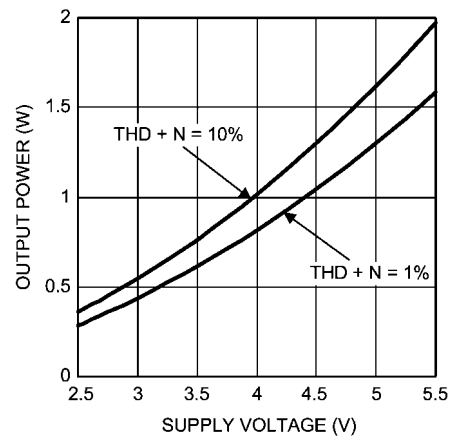
30097514

**Output Power vs Supply Voltage**  
 $f = 1\text{kHz}, R_L = 4\Omega$



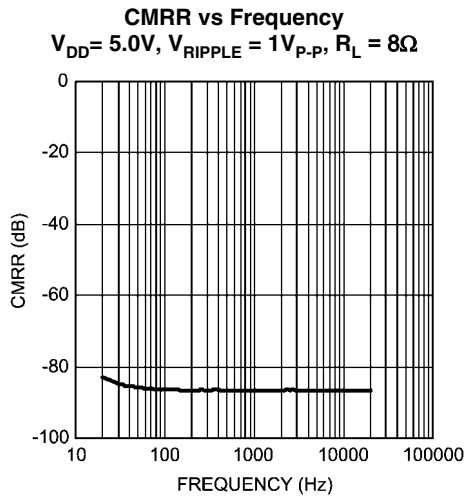
30097515

**Output Power vs Supply Voltage**  
 $f = 1\text{kHz}, R_L = 8\Omega$

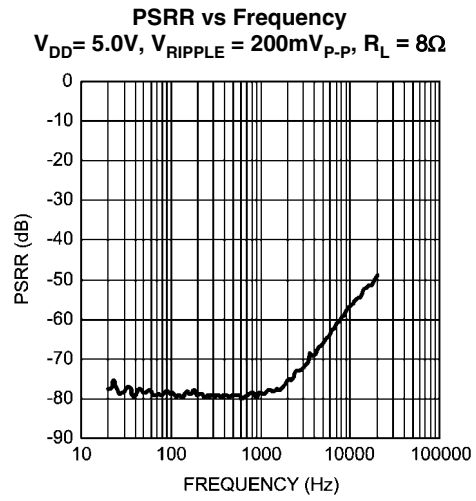


30097516



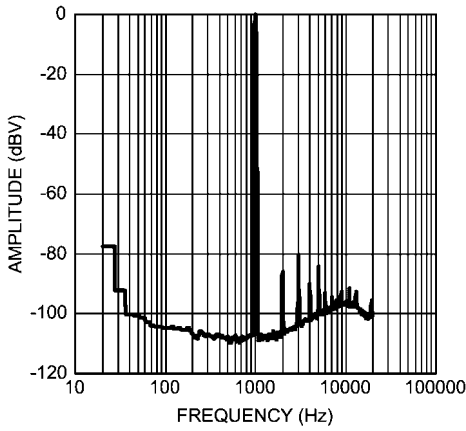


30097529



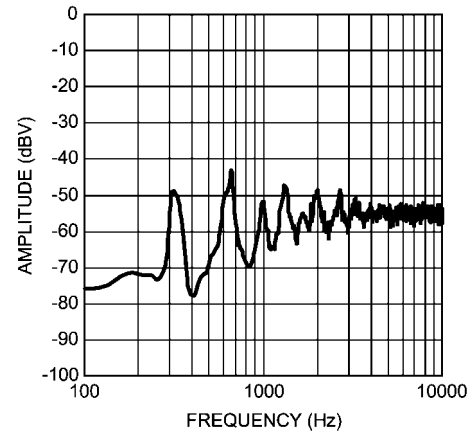
30097517

**Spread Spectrum Output Spectrum vs Frequency**  
 $V_{DD} = 5.0V$ ,  $V_{IN} = 1V_{RMS}$ ,  $R_L = 8\Omega$



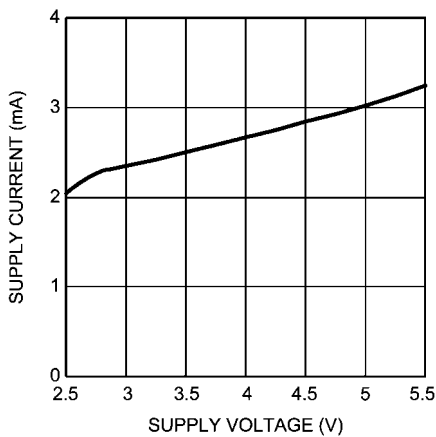
30097519

**Wideband Spread Spectrum Output Spectrum vs Frequency**  
 $V_{DD} = 5.0V$ ,  $R_L = 8\Omega$



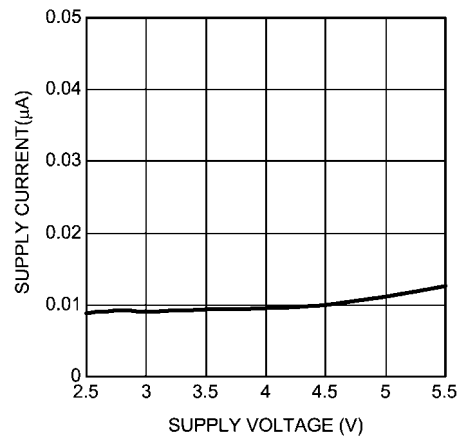
30097520

**Supply Current vs Supply Voltage**  
 No Load



30097521

**Shutdown Supply Current vs Supply Voltage**  
 No Load



30097522

## Application Information

### GENERAL AMPLIFIER FUNCTION

The LM48311 mono Class D audio power amplifier features a filterless modulation scheme that reduces external component count, conserving board space and reducing system cost. The outputs of the device transition from  $V_{DD}$  to GND with a 300kHz switching frequency. With no signal applied, the outputs ( $V_{OUTA}$  and  $V_{OUTB}$ ) switch with a 50% duty cycle, in phase, causing the two outputs to cancel. This cancellation results in no net voltage across the speaker, thus there is no current to the load in the idle state.

With the input signal applied, the duty cycle (pulse width) of the LM48311 outputs changes. For increasing output voltage, the duty cycle of  $V_{OUTA}$  increases, while the duty cycle of  $V_{OUTB}$  decreases. For decreasing output voltages, the converse occurs. The difference between the two pulse widths yields the differential output voltage.

### ENHANCED EMISSIONS SUPPRESSION SYSTEM (E<sup>2</sup>S)

The LM48311 features National's patent-pending E<sup>2</sup>S system that reduces EMI, while maintaining high quality audio reproduction and efficiency. The E<sup>2</sup>S system features spread spectrum and advanced edge rate control (ERC). The LM48311 ERC greatly reduces the high frequency components of the output square waves by controlling the output rise and fall times, slowing the transitions to reduce RF emissions, while maximizing THD+N and efficiency performance. The overall result of the E<sup>2</sup>S system is a filterless Class D amplifier that passes FCC Class B radiated emissions standards with 20in of twisted pair cable, with excellent 0.03% THD+N and high 88% efficiency.

### SPREAD SPECTRUM

The spread spectrum modulation reduces the need for output filters, ferrite beads or chokes. The switching frequency varies randomly by 30% about a 300kHz center frequency, reducing the wideband spectral content, improving EMI emissions radiated by the speaker and associated cables and traces. Where a fixed frequency class D exhibits large amounts of spectral energy at multiples of the switching frequency, the spread spectrum architecture of the LM48311 spreads that energy over a larger bandwidth (See *Typical Performance Characteristics*). The cycle-to-cycle variation of the switching period does not affect the audio reproduction, efficiency, or PSRR.

### DIFFERENTIAL AMPLIFIER EXPLANATION

As logic supplies continue to shrink, system designers are increasingly turning to differential analog signal handling to preserve signal to noise ratios with restricted voltage signs. The LM48311 features a fully differential speaker amplifier. A differential amplifier amplifies the difference between the two input signals. Traditional audio power amplifiers have typically offered only single-ended inputs resulting in a 6dB reduction of SNR relative to differential inputs. The LM48311 also offers the possibility of DC input coupling which eliminates the input coupling capacitors. A major benefit of the fully differential amplifier is the improved common mode rejection ratio (CMRR) over single ended input amplifiers. The increased CMRR of the differential amplifier reduces sensitivity to ground offset related noise injection, especially

### POWER DISSIPATION AND EFFICIENCY

The major benefit of a Class D amplifier is increased efficiency versus a Class AB. The efficiency of the LM48311 is attributed to the region of operation of the transistors in the output stage.

The Class D output stage acts as current steering switches, consuming negligible amounts of power compared to their Class AB counterparts. Most of the power loss associated with the output stage is due to the IR loss of the MOSFET on-resistance, along with switching losses due to gate charge.

### SHUTDOWN FUNCTION

The LM48311 features a low current shutdown mode. Set  $\overline{SD} = GND$  to disable the amplifier and reduce supply current to 0.01 $\mu$ A.

Switch  $\overline{SD}$  between GND and  $V_{DD}$  for minimum current consumption is shutdown. The LM48311 may be disabled with shutdown voltages in between GND and  $V_{DD}$ , the idle current will be greater than the typical 0.1 $\mu$ A value. Increased THD +N may also be observed when a voltage of less than  $V_{DD}$  is applied to  $\overline{SD}$ .

The LM48311 shutdown input has an internal pulldown resistor. The purpose of this resistor is to eliminate any unwanted state changes when  $\overline{SD}$  is floating. To minimize shutdown current,  $\overline{SD}$  should be driven to GND or left floating. If  $\overline{SD}$  is not driven to GND or floating, an increase in shutdown supply current will be noticed.

### AUDIO AMPLIFIER POWER SUPPLY BYPASSING/FILTERING

Proper power supply bypassing is critical for low noise performance and high PSRR. Place the supply bypass capacitors as close to the device as possible. Typical applications employ a voltage regulator with 10 $\mu$ F and 0.1 $\mu$ F bypass capacitors that increase supply stability. These capacitors do not eliminate the need for bypassing of the LM48311 supply pins. A 1 $\mu$ F capacitor is recommended.

### AUDIO AMPLIFIER INPUT CAPACITOR SELECTION

Input capacitors may be required for some applications, or when the audio source is single-ended. Input capacitors block the DC component of the audio signal, eliminating any conflict between the DC component of the audio source and the bias voltage of the LM48311. The input capacitors create a high-pass filter with the input resistors  $R_{IN}$ . The -3dB point of the high pass filter is found using Equation (1) below.

$$f = 1 / 2\pi R_{IN} C_{IN}$$

Where  $R_{IN}$  is the value of the input resistor given in the *Electrical Characteristics* table.

The input capacitors can also be used to remove low frequency content from the audio signal. Small speakers cannot reproduce, and may even be damaged by low frequencies. High pass filtering the audio signal helps protect the speakers. When the LM48311 is using a single-ended source, power supply noise on the ground is seen as an input signal. Setting the high-pass filter point above the power supply noise frequencies, 217Hz in a GSM phone, for example, filters out the noise such that it is not amplified and heard on the output. Capacitors with a tolerance of 10% or better are recommended for impedance matching and improved CMRR and PSRR.

### AUDIO AMPLIFIER GAIN

The gain of the LM48311 is internally set to 6dB. The gain can be reduced by adding additional input resistance (Figure 6). In this configuration, the gain of the device is given by:

$$A_V = 2 \times [R_F / (R_{INEXT} + R_{IN})]$$

Where  $R_F$  is 40k $\Omega$ ,  $R_{IN}$  is 20k $\Omega$ , and  $R_{INEXT}$  is the value of the additional external resistor.

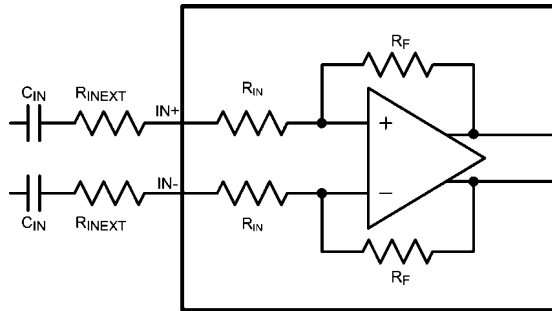


FIGURE 4. Reduced Gain Configuration

30097561

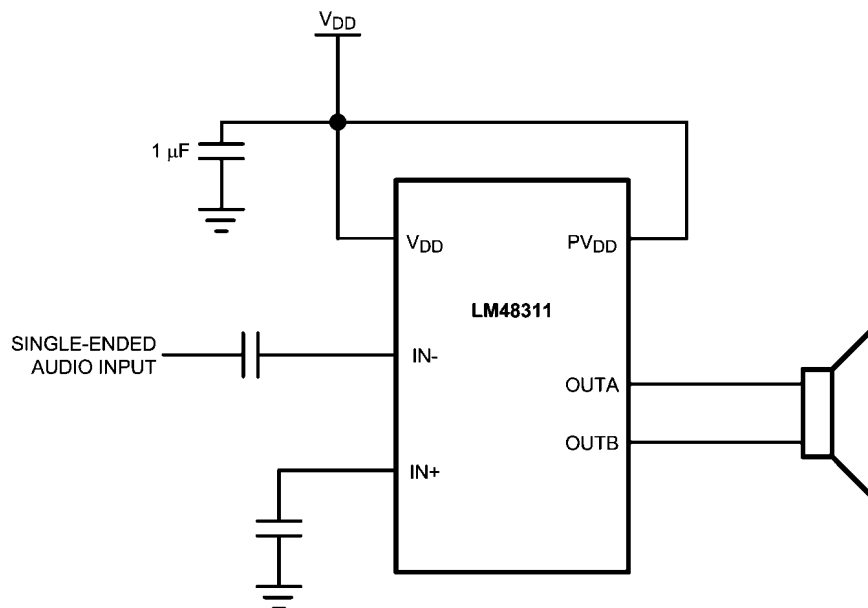


FIGURE 5. Single-Ended Input Configuration

300975a6

### PCB LAYOUT GUIDELINES

As output power increases, interconnect resistance (PCB traces and wires) between the amplifier, load and power supply create a voltage drop. The voltage loss due to the traces between the LM48311 and the load results in lower output power and decreased efficiency. Higher trace resistance between the supply and the LM48311 has the same effect as a poorly regulated supply, increasing ripple on the supply line, and reducing peak output power. The effects of residual trace resistance increases as output current increases due to higher output power, decreased load impedance or both. To maintain the highest output voltage swing and corresponding peak output power, the PCB traces that connect the output pins to the load and the supply pins to the power supply should be as wide as possible to minimize trace resistance.

The use of power and ground planes will give the best THD +N performance. In addition to reducing trace resistance, the

### SINGLE-ENDED AUDIO AMPLIFIER CONFIGURATION

The LM48311 is compatible with single-ended sources. When configured for single-ended inputs, input capacitors must be used to block and DC component at the input of the device. Figure 5 shows the typical single-ended applications circuit.

use of power planes creates parasitic capacitors that help to filter the power supply line.

The inductive nature of the transducer load can also result in overshoot on one of both edges, clamped by the parasitic diodes to GND and  $V_{DD}$  in each case. From an EMI standpoint, this is an aggressive waveform that can radiate or conduct to other components in the system and cause interference. It is essential to keep the power and output traces short and well shielded if possible. Use of ground planes, beads and micro-strip layout techniques are all useful in preventing unwanted interference.

wires or traces acting as antennas become more efficient with length. Ferrite chip inductors placed close to the LM48311 outputs may be needed to reduce EMI radiation.

## BUILD OF MATERIALS

## LM48311TL Demoboard Bill of Materials

Designator	Quantity	Description
C1	1	10 $\mu$ F $\pm$ 10% 16V Tantalum Capacitor (B Case) AVX TPSB106K016R0800
C2	1	1 $\mu$ F $\pm$ 10% 16V X5R Ceramic Capacitor (603) Panasonic ECJ-1VB1C105K
C3, C4	2	1 $\mu$ F $\pm$ 10% 16V X7R Ceramic Capacitor (1206) Panasonic ECJ-3YB1C105K
JU1	1	3-Pin Header
LM48311TL	1	LM48311TL (9-Bump microSMD)

## LM48311 Demo Board Schematic

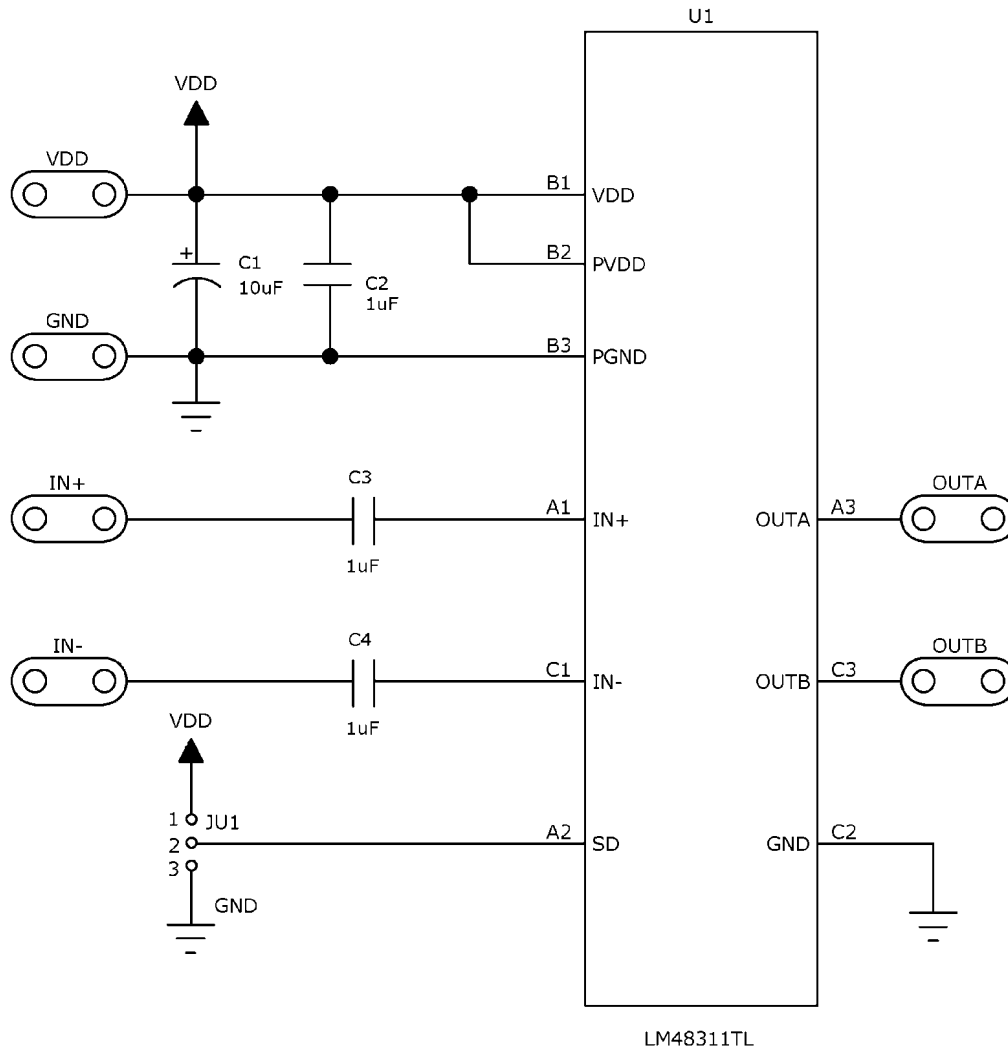


FIGURE 6. LM48311 Demo Board Schematic

30097530

## Demo Boards

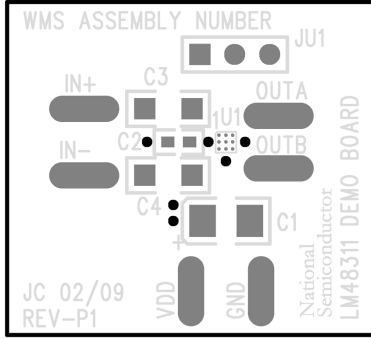


FIGURE 7. Top Silkscreen

30097526

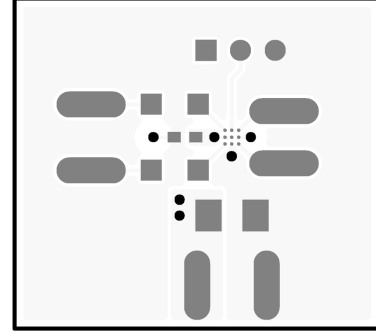


FIGURE 8. Top Layer

30097525

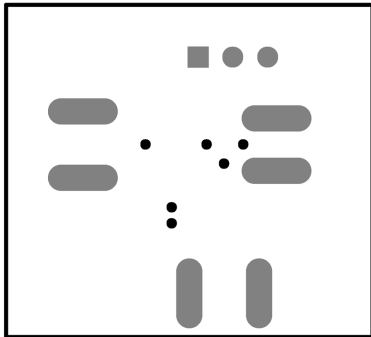


FIGURE 9. Bottom Silkscreen

30097524

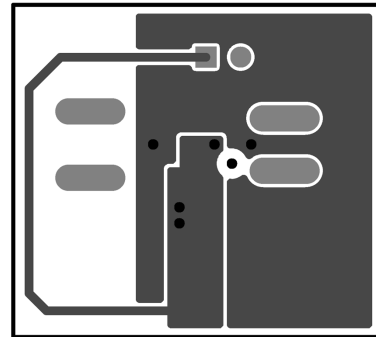


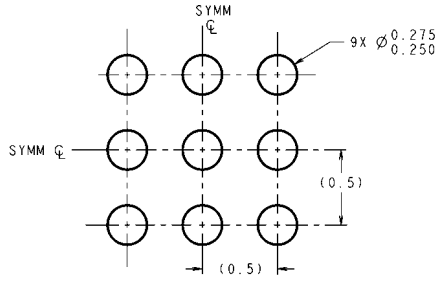
FIGURE 10. Bottom Layer

30097523

## Revision History

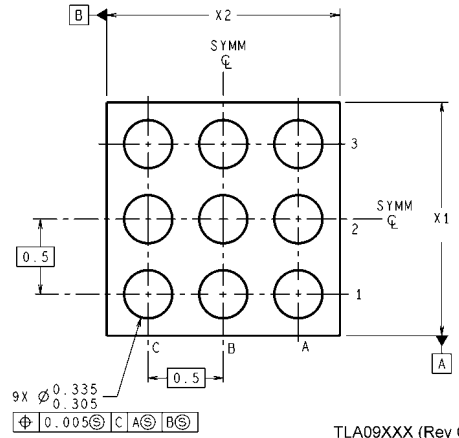
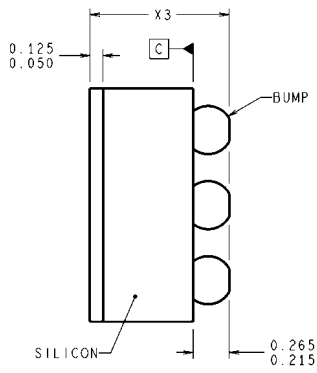
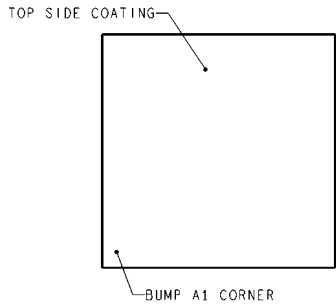
Rev	Date	Description
1.0	06/25/09	Initial released.
1.01	03/17/10	Text edits (under ENHANCED EMISSIONS....)

**Physical Dimensions** inches (millimeters) unless otherwise noted



**DIMENSIONS ARE IN MILLIMETERS**  
DIMENSIONS IN ( ) FOR REFERENCE ONLY

**LAND PATTERN RECOMMENDATION**



TLA09XXX (Rev C)

**9 Bump micro SMD**  
**Order Number LM48311TL**  
**NS Package Number TLA09BCA**  
**X1 = 1.539mm X2 = 1.565mm X3 = 0.6mm**



# Notes

LM4831

## Notes

For more National Semiconductor product information and proven design tools, visit the following Web sites at:  
[www.national.com](http://www.national.com)

Products		Design Support	
Amplifiers	<a href="http://www.national.com/amplifiers">www.national.com/amplifiers</a>	WEBENCH® Tools	<a href="http://www.national.com/webench">www.national.com/webench</a>
Audio	<a href="http://www.national.com/audio">www.national.com/audio</a>	App Notes	<a href="http://www.national.com/appnotes">www.national.com/appnotes</a>
Clock and Timing	<a href="http://www.national.com/timing">www.national.com/timing</a>	Reference Designs	<a href="http://www.national.com/refdesigns">www.national.com/refdesigns</a>
Data Converters	<a href="http://www.national.com/adc">www.national.com/adc</a>	Samples	<a href="http://www.national.com/samples">www.national.com/samples</a>
Interface	<a href="http://www.national.com/interface">www.national.com/interface</a>	Eval Boards	<a href="http://www.national.com/evalboards">www.national.com/evalboards</a>
LVDS	<a href="http://www.national.com/lvds">www.national.com/lvds</a>	Packaging	<a href="http://www.national.com/packaging">www.national.com/packaging</a>
Power Management	<a href="http://www.national.com/power">www.national.com/power</a>	Green Compliance	<a href="http://www.national.com/quality/green">www.national.com/quality/green</a>
Switching Regulators	<a href="http://www.national.com/switchers">www.national.com/switchers</a>	Distributors	<a href="http://www.national.com/contacts">www.national.com/contacts</a>
LDOs	<a href="http://www.national.com/ldo">www.national.com/ldo</a>	Quality and Reliability	<a href="http://www.national.com/quality">www.national.com/quality</a>
LED Lighting	<a href="http://www.national.com/led">www.national.com/led</a>	Feedback/Support	<a href="http://www.national.com/feedback">www.national.com/feedback</a>
Voltage References	<a href="http://www.national.com/vref">www.national.com/vref</a>	Design Made Easy	<a href="http://www.national.com/easy">www.national.com/easy</a>
PowerWise® Solutions	<a href="http://www.national.com/powerwise">www.national.com/powerwise</a>	Applications & Markets	<a href="http://www.national.com/solutions">www.national.com/solutions</a>
Serial Digital Interface (SDI)	<a href="http://www.national.com/sdi">www.national.com/sdi</a>	Mil/Aero	<a href="http://www.national.com/milaero">www.national.com/milaero</a>
Temperature Sensors	<a href="http://www.national.com/tempensors">www.national.com/tempensors</a>	SolarMagic™	<a href="http://www.national.com/solarmagic">www.national.com/solarmagic</a>
PLL/VCO	<a href="http://www.national.com/wireless">www.national.com/wireless</a>	PowerWise® Design University	<a href="http://www.national.com/training">www.national.com/training</a>

THE CONTENTS OF THIS DOCUMENT ARE PROVIDED IN CONNECTION WITH NATIONAL SEMICONDUCTOR CORPORATION ("NATIONAL") PRODUCTS. NATIONAL MAKES NO REPRESENTATIONS OR WARRANTIES WITH RESPECT TO THE ACCURACY OR COMPLETENESS OF THE CONTENTS OF THIS PUBLICATION AND RESERVES THE RIGHT TO MAKE CHANGES TO SPECIFICATIONS AND PRODUCT DESCRIPTIONS AT ANY TIME WITHOUT NOTICE. NO LICENSE, WHETHER EXPRESS, IMPLIED, ARISING BY ESTOPPEL OR OTHERWISE, TO ANY INTELLECTUAL PROPERTY RIGHTS IS GRANTED BY THIS DOCUMENT.

TESTING AND OTHER QUALITY CONTROLS ARE USED TO THE EXTENT NATIONAL DEEMS NECESSARY TO SUPPORT NATIONAL'S PRODUCT WARRANTY. EXCEPT WHERE MANDATED BY GOVERNMENT REQUIREMENTS, TESTING OF ALL PARAMETERS OF EACH PRODUCT IS NOT NECESSARILY PERFORMED. NATIONAL ASSUMES NO LIABILITY FOR APPLICATIONS ASSISTANCE OR BUYER PRODUCT DESIGN. BUYERS ARE RESPONSIBLE FOR THEIR PRODUCTS AND APPLICATIONS USING NATIONAL COMPONENTS. PRIOR TO USING OR DISTRIBUTING ANY PRODUCTS THAT INCLUDE NATIONAL COMPONENTS, BUYERS SHOULD PROVIDE ADEQUATE DESIGN, TESTING AND OPERATING SAFEGUARDS.

EXCEPT AS PROVIDED IN NATIONAL'S TERMS AND CONDITIONS OF SALE FOR SUCH PRODUCTS, NATIONAL ASSUMES NO LIABILITY WHATSOEVER, AND NATIONAL DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY RELATING TO THE SALE AND/OR USE OF NATIONAL PRODUCTS INCLUDING LIABILITY OR WARRANTIES RELATING TO FITNESS FOR A PARTICULAR PURPOSE, MERCHANTABILITY, OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

### LIFE SUPPORT POLICY

**NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS PRIOR WRITTEN APPROVAL OF THE CHIEF EXECUTIVE OFFICER AND GENERAL COUNSEL OF NATIONAL SEMICONDUCTOR CORPORATION.** As used herein:

Life support devices or systems are devices which (a) are intended for surgical implant into the body, or (b) support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in a significant injury to the user. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system or to affect its safety or effectiveness.

National Semiconductor and the National Semiconductor logo are registered trademarks of National Semiconductor Corporation. All other brand or product names may be trademarks or registered trademarks of their respective holders.

Copyright© 2010 National Semiconductor Corporation

For the most current product information visit us at [www.national.com](http://www.national.com)



**National Semiconductor Americas Technical Support Center**  
 Email: [support@nsc.com](mailto:support@nsc.com)  
 Tel: 1-800-272-9959

**National Semiconductor Europe Technical Support Center**  
 Email: [europe.support@nsc.com](mailto:europe.support@nsc.com)

**National Semiconductor Asia Pacific Technical Support Center**  
 Email: [ap.support@nsc.com](mailto:ap.support@nsc.com)

**National Semiconductor Japan Technical Support Center**  
 Email: [jpn.feedback@nsc.com](mailto:jpn.feedback@nsc.com)